substance: Mn_nSi_{2n-m}
property: energy gap, effective masses of $Mn_{11}Si_{19}$, $Mn_{26}Si_{45}$

energy gaps

$E_{g,th}$	≈ 0.5 eV	T = 0 K	from log $\rho \propto E_g/2kT$	69I, 69N1, 72A, 72U
	0.8 eV	T = 0 K		69N2
	≈ 1 eV	T = 0 K	from log $\rho \propto E_g/2kT$ and $S(T)$	74A
$E_{g,dir}$	0.66 eV	RT	from optical absorption	79Z

Near the edge of the valence band there is a narrow d-band whose effective electron mass is 100 times greater than the effective mass of holes [74A].

effective masses

m_n	> 10^3 m_0	T = 300 K		69N2
m_p	10 m_0	T = 300 K		69N2
	3.3 m_0	T = 300 K		74A
	2.7 m_0	T = 300 K	density of states mass	69N1
	3.2 m_0	T = 650 K		

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